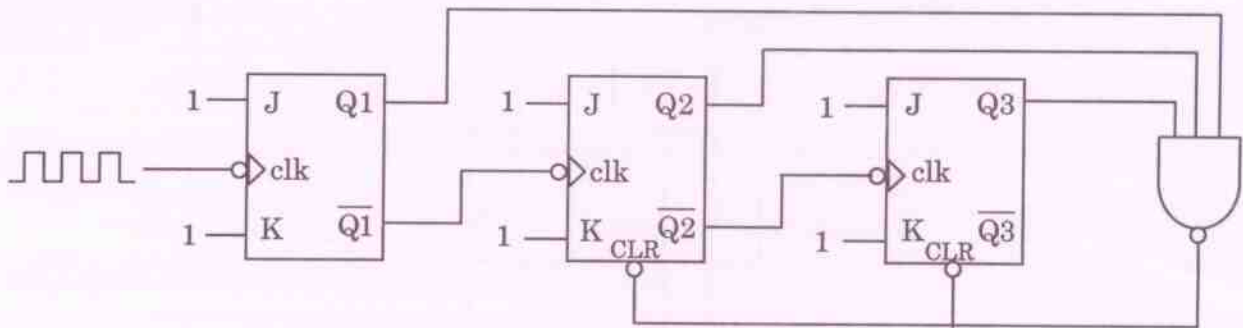


- The approximate O/P Frequency of 555 Oscillator for $R_A = R_B = 2.2 \text{ k}\Omega$ and $C = 2000 \text{ pF}$
 - 110 kHz
 - 109.3 kHz
 - 120.5 kHz
 - 108.9 kHz

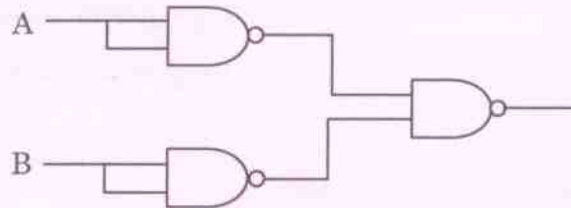
- A counter is designed using J-K Flip-Flop as shown in fig. Define its count sequence



- 000, 001, 010, 011, 100 & repeats
 - 100, 011, 010, 001, 000 & repeat
 - 010, 011, 100, 000, 001 & repeats
 - 101, 110, 111, 000, 001, 010, 011, 100 & repeats
- A 1 MHz clock signal is applied to a J-K Flip Flop with $J=K=1$. What is the frequency of the Flip-Flop O/P signal?
 - 2 MHz
 - 500 kHz
 - 250 kHz
 - 500 MHz
 - How many inputs & outputs does a full adder have?
 - 3, 2
 - 2, 3
 - 3, 3
 - 2, 2
 - Which shift register counter requires the most decoding circuitry?
 - Johnson Counter
 - Ring Counter
 - Ripple Counter
 - MOD counter



11. The output equivalent circuit of following circuit is

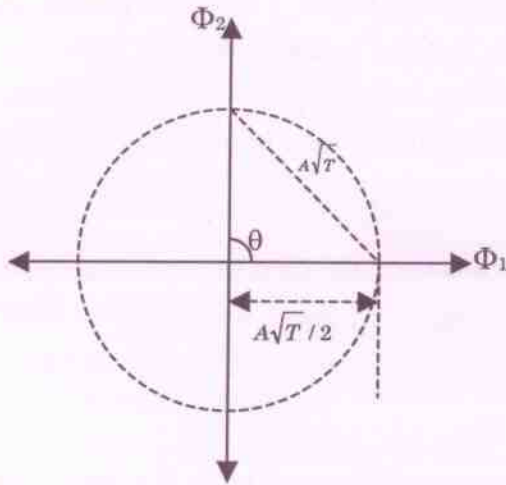


- (a) INVERTER (b) AND
(c) OR (d) NOR
12. A binary source in which 0s occurs 3 times as often as 1s. Then its entropy in bits/symbol will be
(a) 0.75 bits/symbol (b) 0.25 bits/symbol
(c) 0.81 bits/symbol (d) 0.85 bits/symbol
13. Maximum value of signal to noise ratio of an 8-bit ADC with an I/P range of 10 V will be
(a) 50 dB (b) 43.8 dB
(c) 48.9 dB (d) 49.8 dB
14. The available power required at a receiving antenna is 10^{-6} Watts. Transmitting and receiving antennas have gain of 40dB each. The carrier frequency is 4GHz and the distance between them is 30 miles. The required transmitter power is
(a) 0.64 W (b) 0.74 W
(c) 0.78 W (d) 0.32 W
15. An FM signal at 10.7 MHz IF needs to be digitized for demodulation in a digital domain. If the bandwidth of this signal is 200 kHz, the maximum usable sampling frequency is
(a) 200 kHz (b) 600 kHz
(c) 400 kHz (d) 800 kHz
16. A satellite system employs QPSK modulation with 40% excess bandwidth per carrier including guard band. The voice channels use 64 kbps PCM coding. The no. of channels supported by 36 MHz bandwidth of the transponder in bandwidth limited case will be
(a) 1000 (b) 800
(c) 900 (d) 600



17. Hamming codes are used for
- (a) Burst error correction (b) Signal error correction
(c) Both (a) and (b) (d) None of the above
18. Which statement is correct for Schottkey diode?
- (a) Current Voltage characteristics is totally different than that of a p-n junction diode
(b) The current is controlled by the diffusion of minority carriers
(c) The current results from the flow of minority carriers
(d) The storage time t_s is almost zero
19. Photodiodes operate at
- (a) Forward bias (b) Breakdown region
(c) Reverse bias (d) Saturation region
20. The dynamic resistance of diode varies as
- (a) $1/I^2$ (b) $1/I$
(c) I (d) I^2
21. In a p-n diode, with the increase reverse bias, the reverse current
- (a) increases (b) decreases
(c) remain constant (d) - uncertain
22. The Nyquist filter has impulse response given by
- (a) $h(t) = \frac{\sin\left(\frac{\pi t}{T}\right)}{\left(\frac{\pi t}{T}\right)}$ (b) $h(t) = \frac{1}{2} \left(\frac{\sin(\pi t)}{(\pi t)} \right)$
(c) $h(t) = \frac{\sin(\pi t)}{\left(\frac{\pi t}{T}\right)}$ (d) $h(t) = \frac{\cos(\pi t)}{\left(\frac{\pi t}{T}\right)}$

23.



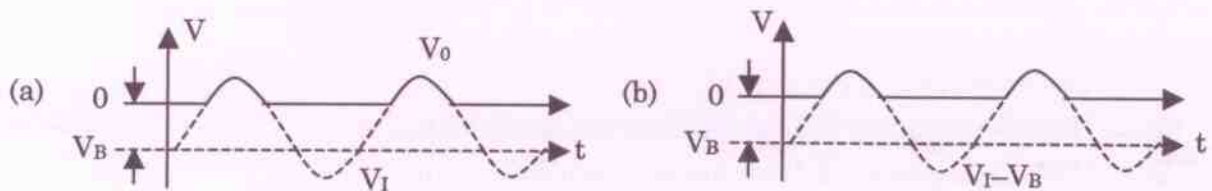
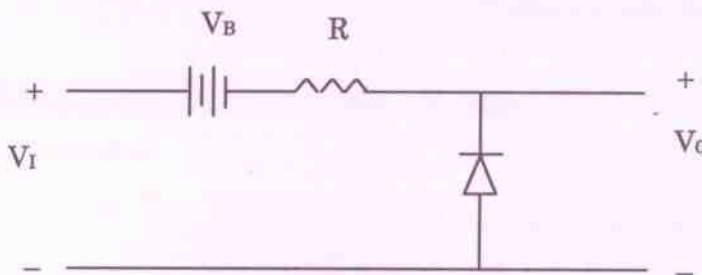
Shown signal space diagram is for

- (a) Quadrature QPSK
- (b) Binary FSK
- (c) Bi-Phase PSK
- (d) MSK

24. Negative feedback in amplifiers

- (a) improves the signal to noise ratio at the I/P
- (b) improves the signal to noise ratio at the O/P
- (c) Doesn't affect the Signal to Noise ratio at the O/P
- (d) All of these

25. Output response of a diode clipper circuit shown in figure will be





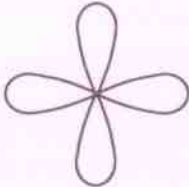

- (c) Both (a) & (b)
- (d) None of the above




26. For an n-channel MOSFET, if conduction parameter (k_n) is 0.249 mA/V^2 , gate to source voltage V_{GS} is $2V_{TN}$ where $V_{TN} = 0.75\text{V}$. The current will be
- (a) 0.160 mA (b) 0.150 mA
(c) 0.140 mA (d) 0.170 mA
27. If $\alpha = 0.98$, $I_{co} = 6 \mu\text{A}$, & $I_R = 100 \mu\text{A}$ for a transistor, then the value of I_C will be
- (a) 2.3 mA (b) 3.1 mA
(c) 4.6 mA (d) 5.2 mA
28. A unit step voltage $2u(t - \theta)$ is applied in a series RC circuit with $R = 2\Omega$, $C = 1F$. Assuming zero initial conditions, find $i(t)$
- (a) $i(t) = u(t) e^{-0.5(t)} A$ (b) $i(t) = u(t - 2\theta) e^{-0.5(t-2\theta)} A$
(c) $i(t) = u(t - \theta) e^{-0.5(t-\theta)} A$ (d) $i(t) = u(t - \theta) e^{-(t-\theta)} A$
29. The autocorrelation of a wide-sense stationary random process is given by $e^{-2|r|}$. The peak value of the spectral density is
- (a) 2 (b) 1
(c) $e^{-1/2}$ (d) e
30. Which of the following gives piezo electric effect?
- (a) μ metal (b) PVDF
(c) Sapphire (d) Ferrite
31. The mean free path for electron drift increases with
- (a) Purity (b) Strain Hardening
(c) Elastic modules (d) None of the above
32. Pure Metals generally have
- (a) High Conductivity & Low temperature coefficient
(b) High Conductivity & High temperature coefficient
(c) Low Conductivity & zero temperature coefficient
(d) Low Conductivity & High temperature coefficient



33. A typical optical fiber has
- (a) high refractive index core & low refractive index cladding
 - (b) Low refractive index core & high refractive index cladding
 - (c) Uniform refractive index core surrounded by variable refractive index cladding
 - (d) None of the above
34. The ceramic materials are
- (a) Inorganic substances
 - (b) Brittle
 - (c) Good Thermal insulators
 - (d) All of the above
35. The best definition of a superconductor is
- (a) It is a material showing perfect conductivity and Meissner effect below a critical temperature
 - (b) It is conductor having zero resistance
 - (c) It is a perfect conductor with highest diamagnetic susceptibility
 - (d) It is a perfect conductor but becomes resistive when the current density through it exceeds a critical value
36. A periodic function of half wave symmetry is necessarily
- (a) an even function
 - (b) an odd function
 - (c) neither odd nor even
 - (d) both odd and even
37. The Fourier transform of a Gaussian time pulse is
- (a) Uniform
 - (b) A pair of impulses
 - (c) Gaussian
 - (d) Rayleigh
38. The covariance function $C_x(\tau)$ of a stationary stochastic process $x(t)$ is said to be positive definite. This means that
- (a) $C_x(\tau) \geq 0$ for all τ
 - (b) $\int_{-\infty}^{\infty} C_x(\tau) d\tau \geq 0$
 - (c) $\int_{-\infty}^{\infty} C_x(\tau) \exp(-j\omega\tau) d\tau \geq 0$
 - (d) $C_x(0) \geq 0$

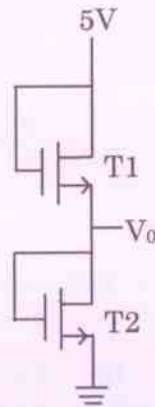
39. If a vertical dipole antenna is used in conjunction with a loop antenna for direction finding, the field pattern obtained will be
- (a)  (b) 
- (c)  (d) 
40. The coding system typically used in digital telemetry is
- (a) PPM (Pulse Position Modulation) (b) PAM (Pulse Amplitude Modulation)
(c) PCM (Pulse Code Modulation) (d) PDM (Pulse Duration Modulation)
41. The temperature coefficient of resistance for a thermister is
- (a) low and negative (b) low and positive
(c) high and negative (d) high and positive
42. Compared to field effect photo transistor, bipolar photo transistors are
- (a) more sensitive and faster (b) less sensitive and slower
(c) more sensitive and slower (d) less sensitive and faster
43. A uniform plane wave in air impinge at 45° angle on a lossless dielectric material with dielectric constant ϵ_r . The transmitted wave propagates in a 30° direction with respect to the normal. The value of ϵ_r is
- (a) 1.5 (b) $\sqrt{1.5}$
(c) 2 (d) $\sqrt{2}$
44. If a donor type impurity is added to the semiconductor, then at a given temperature, the Fermi Level
- (a) Moves towards the center of the energy gap
(b) Moves towards the valence band
(c) Moves towards the conduction band
(d) Doesn't change

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45. Which of the following statement is correct?
- In semiconductors, electron and holes move in an electric field and in the same direction
 - Electric field density is exactly equal to the sum of electric field intensity and polarization
 - Ampere's circuital law states that the line integral of \vec{H} about any closed path is exactly equal to the direct current enclosed by that path
 - None of the above
46. Magnetic field intensity (H), within a magnetic material where, $M = 150 A/m$, $\mu = 1.5 \times 10^{-5} H/m$, $\mu_r = 30$;
- 14.921 A/m
 - 14.138 A/m
 - 1.82 A/m
 - 13.715 A/m
47. A steel pipe is constructed of a material for which $\mu_r = 200$ and $\sigma = 5 \times 10^6$ mho/m. The outer and inner radii are 8 and 6 mm respectively and the length is 80 m. If the total current carried by the pipe is $2\cos 10^4 \pi t$ A, Then the skin depth will be
- 0.225×10^{-3} m
 - 0.300×10^{-3} m
 - 0.352×10^{-3} m
 - 0.125×10^{-3} m
48. A small amount of phosphorus is added to silicon so that there are 2.5×10^{17} conduction electrons per cubic meter and 9.0×10^{14} holes per cubic meter. Let $\mu_e = 0.13 m^2/V.s$ and $\mu_h = 0.05 m^2/V.s$. The resistivity in $\Omega\text{-m}$ will be
- 5.2072
 - 192.042
 - 129.02
 - 0
49. Silicon dioxide is used in ICs
- Because it facilitates the penetration of diffurants
 - Because of its high heat conduction
 - To control the location of diffusion and to protect and insulate the Si Surface
 - To control the concentration of diffurants
50. Evaluate $\int_0^1 \int_0^{\sqrt{1-x^2}} \frac{dx \cdot dy}{(1+x^2+y^2)}$
- $\frac{\pi}{2} [\log(1+\sqrt{2})]$
 - $\frac{\pi}{4} [\log(1+\sqrt{2})]$
 - $\frac{\pi}{2} [\log(1-\sqrt{2})]$
 - $\frac{\pi}{4} [\log(1-\sqrt{2})]$

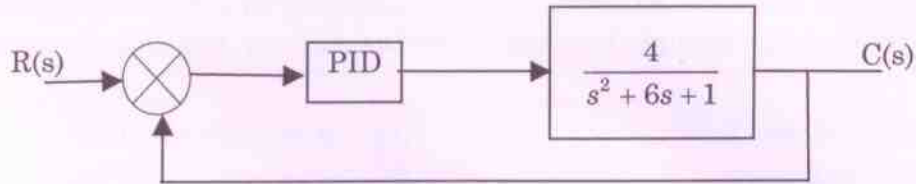


51. Both transistor T1 and T2 in figure have a threshold voltage of 1V. The device parameters K_1 and K_2 of T1 and T2 are $36 \mu A/V^2$ and $9 \mu A/V^2$ respectively. The o/p voltage V_0 is



- (a) 1V (b) 2V
(c) 3V (d) 4V
52. A ramp input applied to a unity feedback system results in 5% steady state error. The type number and zero frequency gain of the system are
- (a) 1 and 20 (b) 0 and 20
(c) 0 and 1/20 (d) 1 and 1/20
53. The magnitude of frequency response of an under-sampled second order system is 5 at 0 rad/sec and peaks to $10/\sqrt{3}$ at $5\sqrt{2}$ rad/sec. The transfer function of the system is
- (a) $\frac{500}{(s^2 + 10s + 100)}$ (b) $\frac{375}{(s^2 + 5s + 75)}$
(c) $\frac{720}{(s^2 + 12s + 144)}$ (d) $\frac{1125}{(s^2 + 25s + 225)}$
54. The system with the open loop transfer function $G(s)H(s) = \frac{1}{s(s^2 + s + 1)}$ has a gain margin of
- (a) -6dB (b) zero
(c) 3.5dB (d) 6dB
55. Given $f(t) = L^{-1} \left[\frac{3s+1}{s^3 + 4s^2 + (k-3)} \right]$, if $\lim_{t \rightarrow \infty} f(t) = 1$, then the value of k is
- (a) 1 (b) 2
(c) 3 (d) 4

61. Find the values of K_P , K_I and K_D for PID controller whose characteristics equation has real roots at 10, $\xi = 0.8$ and $\omega_n = 2 \text{ rad/s}$



- (a) $K_D = 1.8, K_P = 8, K_I = 10$ (b) $K_D = 1.8, K_P = 4, K_I = 5$
 (c) $K_D = 3.6, K_P = 8, K_I = 20$ (d) $K_D = 1.8, K_P = 8, K_I = 20$
62. The transfer function $\left(\frac{1+0.5s}{1+s}\right)$ represents a
- (a) lag network (b) lead network
 (c) lag-lead network (d) proportional controller
63. The wavelength of emitted radiation by electron while transiting from one energy state of -15eV to other energy state of -5eV is
- (a) 1000 \AA (b) 1240 \AA
 (c) 1280 \AA (d) 1300 \AA
64. According to maximum power transfer theorem, maximum power transfer occurs when
- (a) Load R is equal to the half the R of network
 (b) Load R is equal to twice the R of network
 (c) Load R is equal to the R of network looking back at it from voltage terminal
 (d) Load R is equal to the R of network looking back at it from load terminals with all sources being replaced by their respective internal resistance
65. How does the dynamic resistance of diode vary with temperature?
- (a) Directly proportional (b) Inversely proportional
 (c) Independent (d) Directly to the square of temperature

